

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- Dual '245 function
- 25Ω resistor for low noise
- Low propagation delay, zero ground bounce
- Undershoot clamp diodes on all switch and control inputs
- TTL-compatible control inputs
- Available in 40-pin QVSOP package

DESCRIPTION:

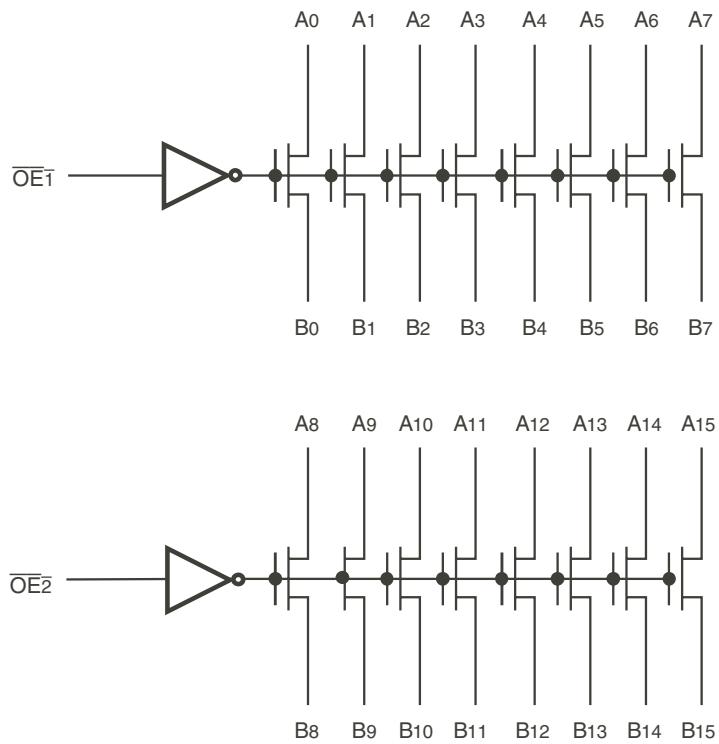
The QS32X2245 provides a set of 16 high-speed CMOS TTL-compatible bus switches in a flow-through pinout. The QS32X2245 includes internal 25Ω resistors to reduce reflection noise in high speed applications. The Output Enable (\overline{OE}_1) signals turn the switches on similar to the \overline{OE} signal of the 74'245.

QuickSwitch devices provide an order of magnitude faster speed than conventional logic devices.

The QS32X2245 is characterized for operation at -40°C to $+85^{\circ}\text{C}$.

APPLICATIONS:

- Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Bus switching and isolation
- Power conservation
- Clock gating
- Logic replacement

FUNCTIONAL BLOCK DIAGRAM

PIN CONFIGURATION

NC	1	40	Vcc
A0	2	39	OE1
A1	3	38	B0
A2	4	37	B1
A3	5	36	B2
A4	6	35	B3
A5	7	34	B4
A6	8	33	B5
A7	9	32	B6
GND	10	31	B7
NC	11	30	Vcc
A8	12	29	OE2
A9	13	28	B8
A10	14	27	B9
A11	15	26	B10
A12	16	25	B11
A13	17	24	B12
A14	18	23	B13
A15	19	22	B14
GND	20	21	B15

QVSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	-0.5 to +7	V
VTERM ⁽³⁾	DC Switch Voltage Vs	-0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage V _{IN}	-0.5 to +7	V
V _{AC}	AC Input Voltage (pulse width \leq 20ns)	-3	V
I _{OUT}	DC Output Current	120	mA
P _{MAX}	Maximum Power Dissipation (T _A = 85°C)	0.92	W
T _{STG}	Storage Temperature	-65 to +150	°C

NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Vcc terminals.
3. All terminals except Vcc.

CAPACITANCE

(T_A = +25°C, f = 1.0MHz, V_{IN} = 0V, V_{OUT} = 0V)

Pins	Typ.	Max. ⁽¹⁾	Unit
Control Pins	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	I/O	Description
OE1, OE2	I	Bus Enable
A _n	I/O	Bus A
B _n	I/O	Bus B

FUNCTION TABLE⁽¹⁾

OE1	OE2	A ₀ - A ₇	A ₈ - A ₁₅	Function
H	H	Z	Z	Disconnect
L	H	B ₀ - B ₇	Z	Connect
H	L	Z	B ₈ - B ₁₅	Connect
L	L	B ₀ - B ₇	B ₈ - B ₁₅	Connect

NOTE:

1. H = HIGH Voltage Level
L = LOW Voltage Level
Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IH}	Input HIGH Level	Guaranteed Logic HIGH for Control Pins	2	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
I_{IN}	Input Leakage Current (Control Inputs) ⁽²⁾	$0\text{V} \leq V_{IN} \leq V_{CC}$	—	± 0.01	± 1	μA
I_{OZ}	Off-State Output Current (Hi-Z)	$0\text{V} \leq V_{OUT} \leq V_{CC}$, Switches OFF	—	± 0.01	± 1	μA
$R_{ON}^{(3)}$	Switch ON Resistance	$V_{CC} = \text{Min.}$, $V_{IN} = 0\text{V}$, $I_{ON} = 30\text{mA}$	18	23	35	Ω
		$V_{CC} = \text{Min.}$, $V_{IN} = 2.4\text{V}$, $I_{ON} = 15\text{mA}$	18	25	40	
V_P	Pass Voltage ⁽²⁾	$V_{IN} = V_{CC} = 5\text{V}$, $I_{OUT} = -5\mu\text{A}$	3.7	4	4.2	V

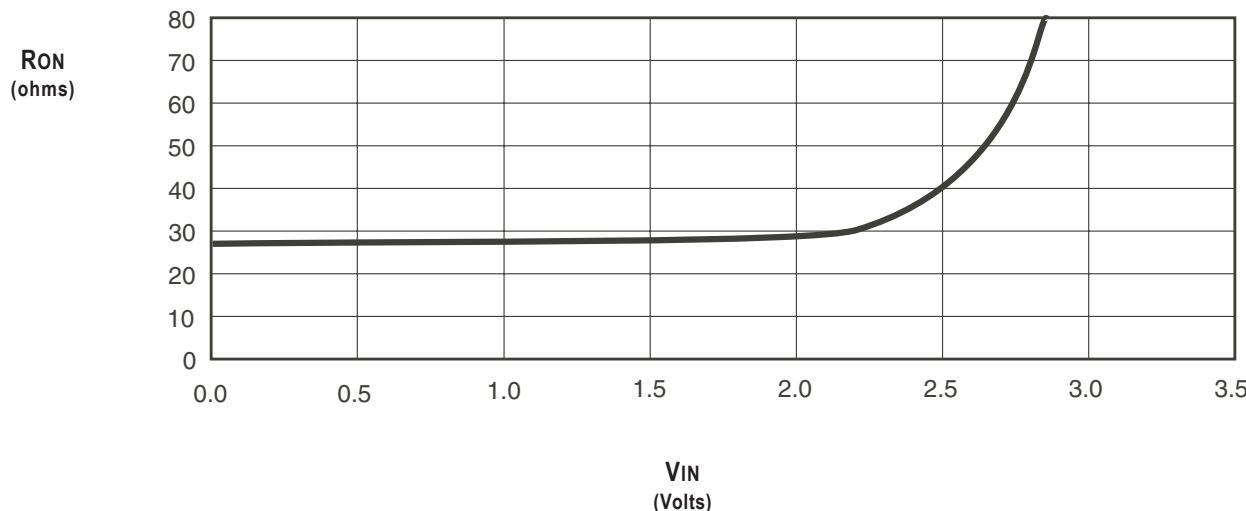
NOTES:

1. Typical values are at $V_{CC} = 5.0\text{V}$, $T_A = 25^\circ\text{C}$.

2. Pass Voltage is guaranteed but not production tested.

3. R_{OUT} changed on March 8, 2002. See rear page for more information.

TYPICAL ON RESISTANCE vs V_{IN} AT $V_{CC} = 5\text{V}$



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
I _{CCQ}	Quiescent Power Supply Current	V _{CC} = Max., V _{IN} = GND or V _{CC} , f = 0	6	µA
ΔI _{CC}	Power Supply Current per Control Input HIGH ⁽²⁾	V _{CC} = Max., V _{IN} = 3.4V, f = 0	1.5	mA
I _{CCD}	Dynamic Power Supply Current per MHz ⁽³⁾	V _{CC} = Max., A and B pins open Control Inputs Toggling at 50% Duty Cycle	0.25	mA/MHz

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
2. Per TLL driven input (V_{IN} = 3.4V, control inputs only). A and B pins do not contribute to ΔI_{CC}.
3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T_A = -40°C to +85°C, V_{CC} = 5.0V ± 5%;

C_{LOAD} = 50pF, R_{LOAD} = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Typ.	Max.	Unit
t _{PLH}	Data Propagation Delay ^(2,3)	—	—	1.25	ns
t _{PHL}	An to/from Bn				
t _{PZL}	Switch Turn-on Delay	0.5	—	6.6	ns
t _{PZH}	OE to An/Bn				
t _{PLZ}	Switch Turn-off Delay ⁽²⁾	0.5	—	4.5	ns
t _{PHZ}	OE to An/Bn				

NOTES:

1. Minimums are guaranteed but not production tested.
2. This parameter is guaranteed but not production tested.
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 1.25ns for C_L = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION

QS	XXXXX	XX	X	X		
	Device Type	Package	Process			
				Blank	Tube or Tray 8 Tape and Reel	
				Blank	Industrial (-40°C to +85°C)	
				Q2G	40-Pin QVSOP - Green	
				32X2245	High Speed CMOS QuickSwitch Double Width Bus Switch	

As per PCN L0201-02, the Output Resistance (R_{ON}) specifications have changed as of March 8, 2002. The original specifications were:

Parameter	Description	Min.	Typ.	Max.	Unit
RON	$V_{CC} = \text{Min}, V_{IN} = 0V, I_{ON} = 30mA$	20	28	40	Ω
	$V_{CC} = \text{Min}, V_{IN} = 2.4V, I_{ON} = 15mA$	20	35	48	

Datasheet Document History

02/16/2011 Pg. 5 Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding Tape and Reel information.

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